#### INTEGRATED CIRCUITS

# DATA SHEET

## 74ABT16244A 74ABTH16244A

16-bit buffer/line driver (3-State)

Product specification Supersedes data of 1998 Feb 25 IC23 Data Handbook







Philips Semiconductors Product specification

### 16-bit buffer/line driver (3-State)

### 74ABT16244A 74ABTH16244A

#### **FEATURES**

- 16-bit bus interface
- Multiple V<sub>CC</sub> and GND pins minimize switching noise
- Power-up 3-State
- 3-State buffers
- Output capability: +64 mA/-32mA
- Live insertion/extraction permitted
- Latch-up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000 V per MIL STD 883 Method 3015 and 200 V per Machine Model
- 74ABTH16244A incorporates bus hold data inputs which eliminate the need for external pull up resistors to hold unused inputs
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs

#### **DESCRIPTION**

The 74ABT16244A high-performance BiCMOS device combines low static and dynamic power dissipation with high speed and high output drive.

The 74ABT16244A device is a 16-bit buffer that is ideal for driving bus lines. The device features four Output Enables (10E, 20E, 30E, 40E), each controlling four of the 3-State outputs.

Two options are available, 74ABT16244A which does not have the bus hold feature and 74ABTH16244A which incorporates the bus hold feature.

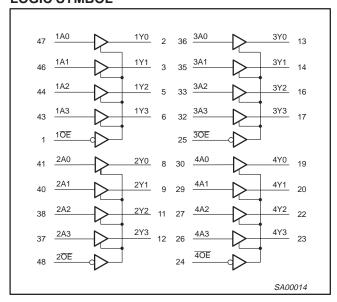
#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T <sub>amb</sub> = 25°C; GND = 0V	TYPICAL	UNIT
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay nAx to nYx	$C_L = 50pF; V_{CC} = 5V$	1.7 2.1	ns
C <sub>IN</sub>	Input capacitance	$V_I = 0V \text{ or } V_{CC}$	4	pF
C <sub>OUT</sub>	Output capacitance	V <sub>O</sub> = 0V or V <sub>CC</sub> ; 3-State	7	pF
I <sub>CCZ</sub>	Quiescent supply current	Outputs disabled; V <sub>CC</sub> = 5.5V	450	μΑ
I <sub>CCL</sub>	Quiescent supply current	Outputs low; $V_{CC} = 5.5V$	10	mA

#### **ORDERING INFORMATION**

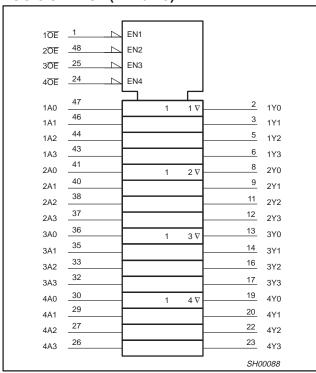
PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
48-Pin Plastic SSOP Type III	-40°C to +85°C	74ABT16244A DL	BT16244A DL	SOT370-1
48-Pin Plastic TSSOP Type II	-40°C to +85°C	74ABT16244A DGG	BT16244A DGG	SOT362-1
48-Pin Plastic SSOP Type III	-40°C to +85°C	74ABH16244A DL	BH16244A DL	SOT370-1
48-Pin Plastic TSSOP Type II	-40°C to +85°C	74ABH16244A DGG	BH16244A DGG	SOT362-1

#### LOGIC SYMBOL

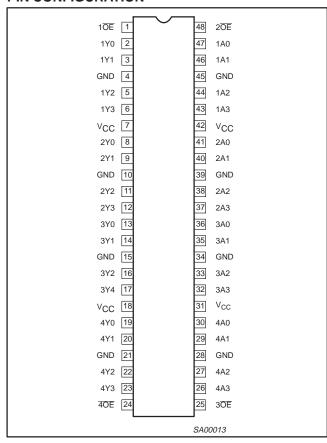


#### 74ABT16244A 74ABTH16244A

#### LOGIC SYMBOL (IEEE/IEC)



#### **PIN CONFIGURATION**



#### **PIN DESCRIPTION**

PIN NUMBER	SYMBOL	NAME AND FUNCTION			
47, 46, 44, 43 41, 40, 38, 37 36, 35, 33, 32 30, 29, 27, 26	1A0 – 1A3, 2A0 – 2A3, 3A0 – 3A3, 4A0 – 4A3	Data inputs			
2, 3, 5, 6 8, 9, 11, 12 13, 14, 16, 17 19, 20, 22, 23	1Y0 - 1Y3, 2Y0 - 2Y3, 3Y0 - 3Y3, 4Y0 - 4Y3	Data outputs			
1, 48 25, 24	1 <u>OE</u> , 2 <u>OE</u> , 3 <u>OE</u> , 4 <u>OE</u>	Output enables			
4, 10, 15, 21 28, 34, 39, 45	GND	Ground (0V)			
7, 18, 31, 42	V <sub>CC</sub>	Positive supply voltage			

#### **FUNCTION TABLE**

INP	OUTPUTS	
nOE	nAx	nYx
L	L	L
L	Н	Н
Н	Х	z

H = High voltage level

L = Low voltage level

X = Don't care

3

Z = High impedance "off" state

#### ABSOLUTE MAXIMUM RATINGS<sup>1, 2</sup>

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V <sub>CC</sub>	DC supply voltage		-0.5 to +7.0	V
I <sub>IK</sub>	DC input diode current	V <sub>I</sub> < 0	-18	mA
V <sub>I</sub>	DC input voltage <sup>3</sup>		-1.2 to +7.0	V
I <sub>OK</sub>	DC output diode current	V <sub>O</sub> < 0	-50	mA
V <sub>OUT</sub>	DC output voltage <sup>3</sup>	output in Off or High state	-0.5 to +5.5	V
	DC output ourront	output in Low state	128	m^
Гоит	DC output current	output in High state	-64	mA
T <sub>stg</sub>	Storage temperature range		-65 to 150	°C

#### NOTES:

#### **RECOMMENDED OPERATING CONDITIONS**

CVMDOL	DADAMETED	LIM	UNIT	
SYMBOL	PARAMETER	MIN	MAX	UNII
V <sub>CC</sub>	DC supply voltage	4.5	5.5	V
V <sub>I</sub>	Input voltage	0	V <sub>CC</sub>	V
V <sub>IH</sub>	High-level input voltage	2.0		V
$V_{IL}$	Low-level input voltage		0.8	V
I <sub>OH</sub>	High-level output current		-32	mA
I <sub>OL</sub>	Low-level output current		64	mA
Δt/Δν	Input transition rise or fall rate	0	10	ns/V
T <sub>amb</sub>	Operating free-air temperature range	-40	+85	°C

Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the
device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to
absolute-maximum-rated conditions for extended periods may affect device reliability.

<sup>2.</sup> The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

<sup>3.</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

#### DC ELECTRICAL CHARACTERISTICS

				1		LIMITS				
SYMBOL	PARAMETER	TEST CO	T <sub>ai</sub>	<sub>mb</sub> = +25	i∘C	T <sub>amb</sub> = -40°C to +85°C		UNIT		
				Min	Тур	Max	Min	Max	1	
V <sub>IK</sub>	Input clamp voltage	$V_{CC} = 4.5V; I_{IK} = -18m$	Α		-0.9	-1.2		-1.2	V	
		$V_{CC} = 4.5V; I_{OH} = -3m$	A; $V_I = V_{IL}$ or $V_{IH}$	2.5	2.9		2.5			
$V_{OH}$	High-level output voltage	$V_{CC} = 5.0V; I_{OH} = -3m$	A; $V_I = V_{IL}$ or $V_{IH}$	3.0	3.4		3.0		V	
		$V_{CC} = 4.5V; I_{OH} = -32r$	mA; $V_I = V_{IL}$ or $V_{IH}$	2.0	2.4		2.0			
$V_{OL}$	Low-level output voltage	$V_{CC} = 4.5V; I_{OL} = 64m.$	A; $V_I = V_{IL}$ or $V_{IH}$		0.42	0.55		0.55	V	
II	Input leakage current	$V_{CC} = 5.5V; V_I = GND$	or 5.5V		±0.01	±1.0		±1.0	μΑ	
	Input leakage current	$V_{CC} = 5.5V; V_I = V_{CC}$ or GND	Control pins		±0.01	±1		±1		
I <sub>I</sub>	74ABTH16244A	$V_{CC} = 5.5V$ ; $V_I = V_{CC}$	Data Pins		0.01	1		1	μΑ	
		$V_{CC} = 5.5V; V_I = 0$	Data Filis	Î	-2	-3		<b>-</b> 5	1 l	
	Due Held sums of A female4	$V_{CC} = 4.5V; V_I = 0.8V$ $V_{CC} = 4.5V; V_I = 2.0V$		50			50		μА	
I <sub>HOLD</sub>	Bus Hold current A inputs <sup>4</sup> 74ABTH16244A			-75			-75			
		$V_{CC} = 5.5V$ ; $V_I = 0$ to 5.5V		±500						
I <sub>OFF</sub>	Power-off leakage current	$V_{CC} = 0.0V$ ; $V_O$ or $V_I \le$	4.5V		±5.0	±100		±100	μΑ	
I <sub>PU</sub> /I <sub>PD</sub>	Power-up/down 3-State output current	$V_{\underline{CC}} = 2.0V; V_{\underline{O}} = 0.5V$ $V_{\underline{OE}} = V_{\underline{CC}}$	$V_I = GND \text{ or } V_{CC};$		±5.0	±50		±50	μΑ	
I <sub>OZH</sub>	3-State output High current	$V_{CC} = 5.5V; V_{O} = 5.5V$	$V_{I} = V_{IL} \text{ or } V_{IH}$		0.1	10		10	μΑ	
I <sub>OZL</sub>	3-State output Low current	$V_{CC} = 5.5V; V_{O} = 0.0V$	$V_{I} = V_{IL} \text{ or } V_{IH}$		-0.1	-10		-10	μΑ	
I <sub>CEX</sub>	Output High leakage current	$V_{CC} = 5.5V; V_{O} = 5.5V$	$V_I = GND \text{ or } V_{CC}$		5.0	50		50	μΑ	
I <sub>O</sub>	Output current <sup>1</sup>	$V_{CC} = 5.5V; V_{O} = 2.5V$		-50	-100	-180	-50	-180	mA	
I <sub>CCH</sub>		V <sub>CC</sub> = 5.5V; Outputs Hi	gh, $V_I = GND$ or $V_{CC}$		0.45	1.0		1.0	mA	
I <sub>CCL</sub>	Quiescent supply current <sup>3</sup>	V <sub>CC</sub> = 5.5V; Outputs Lo	ow, $V_I = GND$ or $V_{CC}$		10	19		19	mA	
I <sub>CCZ</sub>		$V_{CC}$ = 5.5V; Outputs 3-State; $V_I$ = GND or $V_{CC}$			0.45	1.0		1.0	μА	
		Outputs enabled, one of other inputs at V <sub>CC</sub> or 0	data input at 3.4V, GND; V <sub>CC</sub> = 5.5V		100	250		250		
$\Delta I_{CC}$	Additional supply current per input pin <sup>2, 3</sup>	Outputs disabled, one data input at 3.4V, other inputs at $V_{CC}$ or GND; $V_{CC} = 5.5V$			100	250		250	μΑ	
	1,200	Control pins, outputs di input at 3.4V, other input V <sub>CC</sub> = 5.5V			100	250		250		

1. Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

5

- This is the increase in supply current for each input at 3.4V.
   This data sheet limit may vary among suppliers.
   This is the bus hold overdrive current required to force the input to the opposite logic state.

#### **AC CHARACTERISTICS**

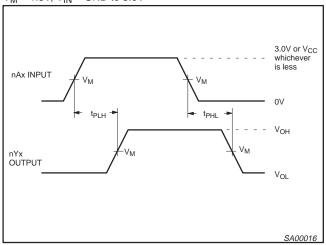
GND = 0V;  $t_R$  =  $t_F$  = 2.5ns;  $C_L$  = 50pF,  $R_L$  = 500 $\Omega$ 

			LIMITS					
SYMBOL	PARAMETER	WAVEFORM	Ţ	<sub>amb</sub> = +25°( V <sub>CC</sub> = +5.0V	Ç	$T_{amb} = -40^{\circ}$ $V_{CC} = +5.$	UNIT	
			MIN	TYP	MAX	MIN	MAX	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay nAx to nYx	1	1.1 1.3	1.7 2.1	2.6 2.9	1.1 1.3	2.8 3.4	ns
t <sub>PZH</sub> t <sub>PZL</sub>	Output enable time to High and Low level	2	1.6 2.3	2.7 3.5	3.7 4.0	1.6 2.3	4.5 4.8	ns
t <sub>PHZ</sub>	Output disable time from High and Low level	2	2.0 1.6	3.0 2.4	4.0 3.2	2.0 1.6	4.6 4.1	ns

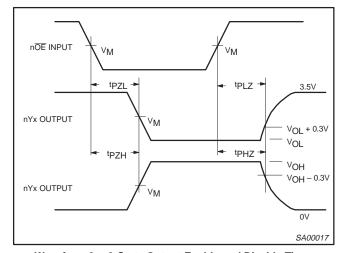
6

#### **AC WAVEFORMS**

 $V_M = 1.5V$ ,  $V_{IN} = GND$  to 3.0V



Waveform 1. Input (An) to Output (Yn) Propagation Delays



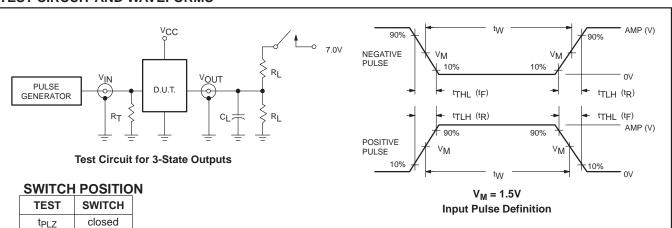
Waveform 2. 3-State Output Enable and Disable Times

Philips Semiconductors Product specification

### 16-bit buffer/line driver (3-State)

74ABT16244A 74ABTH16244A

#### **TEST CIRCUIT AND WAVEFORMS**



### DEFINITIONS

closed

open

 $t_{\mathsf{PZL}}$ 

All other

R<sub>L</sub> = Load resistor; see AC CHARACTERISTICS for value.

 $C_L = Load$  capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

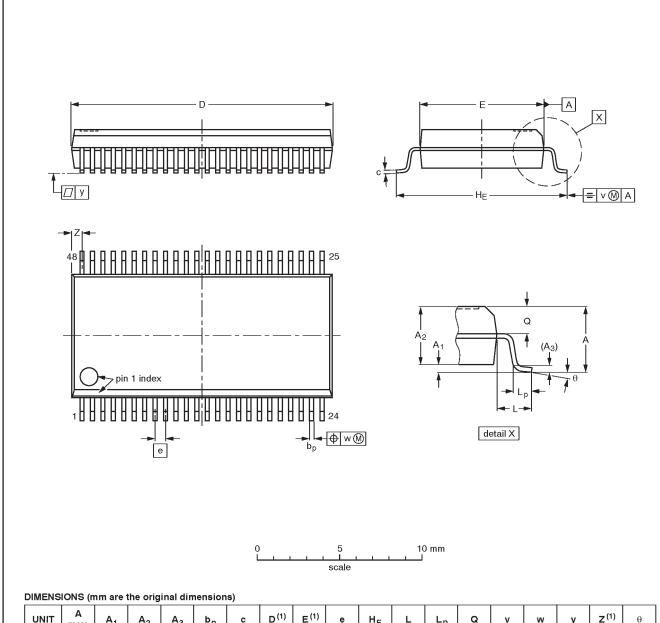
 $\label{eq:RT} \begin{aligned} R_T = & & \text{Termination resistance should be equal to } Z_{OUT} \text{ of } \\ & & \text{pulse generators.} \end{aligned}$ 

FAMILY	INPUT PULSE REQUIREMENTS							
FAMILI	Amplitude	Rep. Rate	t <sub>W</sub>	t <sub>R</sub>	t <sub>F</sub>			
74ABT/H16	3.0V	1MHz	500ns	2.5ns	2.5ns			

A00018

#### SSOP48: plastic shrink small outline package; 48 leads; body width 7.5 mm

SOT370-1



UNIT	A max.	Α1	A <sub>2</sub>	<b>A</b> <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	2.8	0.4 0.2	2.35 2.20	0.25	0.3 0.2	0.22 0.13	16.00 15.75	7.6 7.4	0.635	10.4 10.1	1.4	1.0 0.6	1.2 1.0	0.25	0.18	0.1	0.85 0.40	8° 0°

#### Note

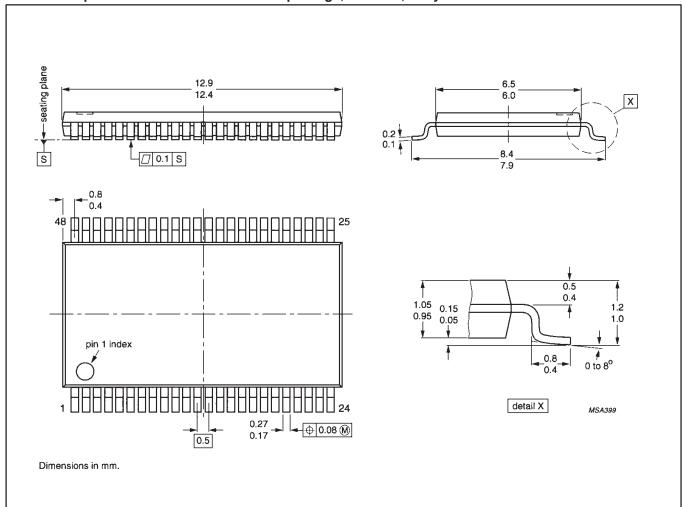
1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT370-1		MO-118AA				<del>93-11-02</del> 95-02-04

74ABT16244A 74ABTH16244A

TSSOP48: plastic thin shrink small outline package; 48 leads; body width 6.1mm





#### Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

<sup>[1]</sup> Please consult the most recently issued datasheet before initiating or completing a design.

#### **Definitions**

**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

**Application information** — Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors make no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

#### **Disclaimers**

**Life support** — These products are not designed for use in life support appliances, devices or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips Semiconductors customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips Semiconductors for any damages resulting from such application.

Right to make changes — Philips Semiconductors reserves the right to make changes, without notice, in the products, including circuits, standard cells, and/or software, described or contained herein in order to improve design and/or performance. Philips Semiconductors assumes no responsibility or liability for the use of any of these products, conveys no license or title under any patent, copyright, or mask work right to these products, and makes no representations or warranties that these products are free from patent, copyright, or mask work right infringement, unless otherwise specified.

Philips Semiconductors 811 East Arques Avenue P.O. Box 3409 Sunnyvale, California 94088–3409 Telephone 800-234-7381 © Copyright Philips Electronics North America Corporation 1998 All rights reserved. Printed in U.S.A.

print code Date of release: 05-96

Document order number: 9397-750-04709

Let's make things better.

Philips Semiconductors



